

Ultrafast Enhancement of Interfacial Exchange Coupling in Ferromagnetic Bilayer

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Fast spin manipulation in magnetic heterostructures, where magnetic interactions between different materials often define the functionality of devices, is a key issue in the development of ultrafast spintronics. Although recently developed optical approaches such as ultrafast spin-transfer and spin-orbit torques open new pathways to fast spin manipulation, these processes do not fully utilize the unique possibilities offered by interfacial magnetic coupling effects in ferromagnetic multilayer systems. Here, we experimentally demonstrate ultrafast photo-enhanced interfacial exchange interactions in the ferromagnetic $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ system at low laser fluence levels. The excitation efficiency of Co_2FeAl with the $(\text{Ga,Mn})\text{As}$ layer is 30-40 times higher than the case with the GaAs layer at 5 K due to a photo-enhanced exchange coupling interaction via photoexcited charge transfer between the two ferromagnetic layers. In addition, the coherent spin precessions persist to room temperature, excluding the drive of photo-enhanced magnetization in the $(\text{Ga,Mn})\text{As}$ layer and indicating a proximity-effect-related optical excitation mechanism. The results highlight the importance of considering the range of interfacial exchange interactions in ferromagnetic heterostructures and how these magnetic coupling effects can be utilized for ultrafast, low-power spin manipulation.

INTRODUCTION

Ultrafast optical control of coherent spin dynamics in ferromagnetic heterostructures is currently of great interest because of its significance in spintronic devices and magnetic recording [1–9]. An overwhelming amount of research is devoted to discovering non-thermal, low-power excitation processes to circumvent the disadvantages associate with thermal mechanisms [10–16]. One promising approach is to make use of the interaction between selectively photo-excited carriers and magnetization since the photo-carrier recombination time is considerably shorter than the thermal dissipation process. Accordingly, it is ideal to utilize the exchange-coupled ferromagnetic systems, as their magnetic properties may respond notably to a small alteration of the exchange-coupling strength [17, 18]. Therefore, the combination of a ferromagnetic (FM) metal and a FM semiconductor is specifically favorable for such a purpose of low-power spin manipulation because the FM semiconductor may have pronounced carrier effect on the magnetic properties [19]. Recent studies demonstrated femtosecond optical control of coercivity [20] and complete reversal of magnetic hysteresis loop [21–23] in $(\text{Ga,Mn})\text{As}$. Nevertheless, the question is still open whether it is possible to drive FM magnetization at low laser fluence through exchange coupling across metal/semiconductor heterostructure interface.

In this article, ultrafast optical excitation of coherent spin precession is investigated in the exchange-coupled $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ bilayer with time-resolved

magneto-optic Kerr effect (TRMOKE). Upon the photoexcitation of electron carriers in $(\text{Ga,Mn})\text{As}$, a nonequilibrium charge current is induced through the heterojunction to the majority spin bands of Co_2FeAl , which enhances the interfacial exchange coupling. The photo-excited coherent spin precession persist to room temperature, though the precession amplitude drops significantly around the Curie temperature of $(\text{Ga,Mn})\text{As}$, indicating that the proximity effect plays an essential role in the optical excitation mechanism of coherent spin precession in $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ bilayer. Our results promote the development of low-energy consumption magnetic device concepts for fast spin manipulation.

RESULTS

Outline of the experiments

Our experimental system is a FM exchange-coupled bilayer heterostructure, composed of a near half-metallic Heusler alloy Co_2FeAl and a FM semiconductor $(\text{Ga,Mn})\text{As}$ (Fig. 1), epitaxially grown on GaAs (001) substrate by molecular beam epitaxy (MBE) (see Methods) [24]. The 10-nm thick Co_2FeAl layer shows an in-plane uniaxial magnetic anisotropy with an easy axis along the [110] direction (Fig. 1(b)), while the 150-nm thick $(\text{Ga,Mn})\text{As}$ film reveals an easy axis along the [1-10] direction below the Curie temperature $T_c = 50$ K [24], as revealed by the minor loop in Fig. 1(c).

Due to the strong coupling at the interface and the rel-

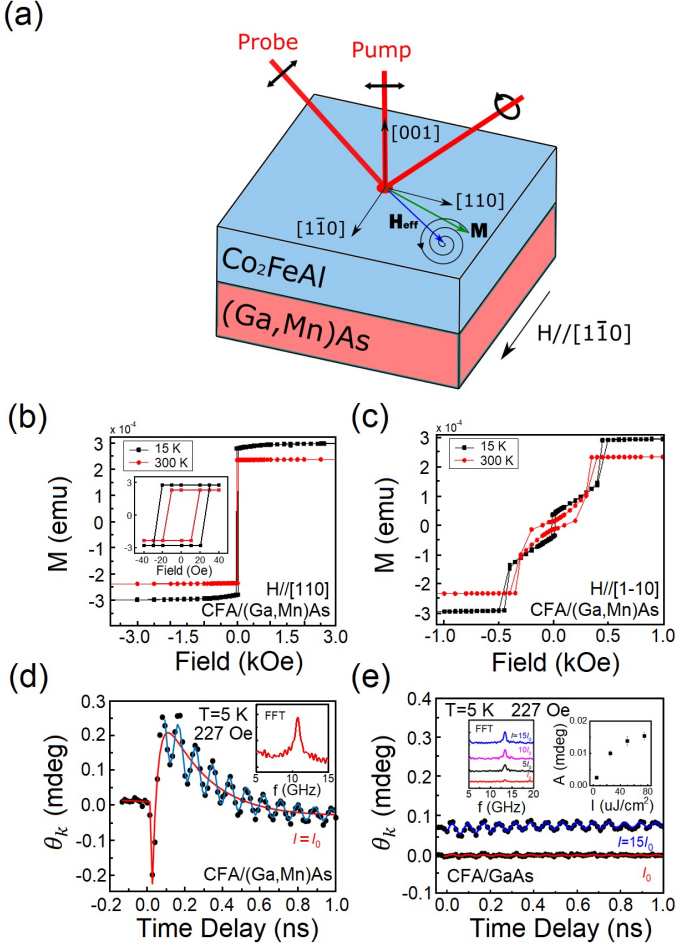


FIG. 1. Schematic illustration of TRMOKE experiments, SQUID measurements, and experimental observation of ultrafast enhanced interfacial exchange interaction. (a) Schematic of TRMOKE measurement geometry, depicting the structure of the sample and the magnetization \mathbf{M} precessing around the effective field \mathbf{H}_{eff} in $\text{Co}_2\text{FeAl}/(\text{Ga},\text{Mn})\text{As}$ bilayer in a canted magnetization configuration with \mathbf{H} applied along hard axis [1-10]. (b) SQUID measurement in $\text{Co}_2\text{FeAl}/(\text{Ga},\text{Mn})\text{As}$ bilayer along the easy axis [110] direction. The inset shows the close-up around zero magnetic field. (c) SQUID measurement in $\text{Co}_2\text{FeAl}/(\text{Ga},\text{Mn})\text{As}$ bilayer along the hard axis [1-10] direction. (d) TRMOKE data from $\text{Co}_2\text{FeAl}/(\text{Ga},\text{Mn})\text{As}$ bilayer at 5 K, exhibiting the initial demagnetization (-0.41 mdeg) and the subsequent 100-ps magnetization rise (0.46 mdeg) and uniform spin precession. The red and blue curves are fits of LLG equation. The inset shows the FFT analysis of precession frequency. (e) TRMOKE data from Co_2FeAl layer without $(\text{Ga},\text{Mn})\text{As}$ layer at 5 K. The FFT analysis for precession frequency and the precession amplitude as a function of pump-energy density are shown as insets.

actively strong cubic anisotropy constant K_1 of Co_2FeAl , the interfacial spin alignment of the $(\text{Ga},\text{Mn})\text{As}$ layer should be very close to that in the Co_2FeAl layer [24]. At low temperature ($T < T_c$) a ferromagnetic alignment of Mn spins in the $(\text{Ga},\text{Mn})\text{As}$ layer is expected, whereas

at high temperatures ($T > T_c$) Mn ions extending a few nanometers in the $(\text{Ga},\text{Mn})\text{As}$ layer remain spin-polarized due to the ferromagnetic proximity effect [24]. Such a FM metal/semiconductor heterostructure is ideal for examining the interfacial magnetic interactions, due to their different magnetic anisotropy and strong interfacial exchange coupling. Furthermore, one can envision an additional level of optoelectronic control over the underlying exchange interaction due to the existence of spin polarized carriers in the bilayer system.

Observation of ultrafast photo-enhanced exchange interactions

Coherent spin precessions in $\text{Co}_2\text{FeAl}/(\text{Ga},\text{Mn})\text{As}$ bilayer and a reference sample of the $\text{Co}_2\text{FeAl}/\text{GaAs}$ bilayer are investigated by near-infrared ($\lambda = 800$ nm), low-fluence ($I_0 = 5 \mu\text{J}/\text{cm}^2$), pump-probe TRMOKE measurements (see Methods) in a canted magnetization configuration where the magnetic field (\mathbf{H}) is applied along the hard axis [1-10], as depicted in Fig. 1(a). In equilibrium, the magnetization \mathbf{M} is along an effective field \mathbf{H}_{eff} , which is the sum of \mathbf{H} , the demagnetizing field, the anisotropy fields, and the exchange-coupling field (see Supplementary). The s-polarized incident pump pulses create a short yet strong spin torque $\tau(t)$ in the FM-coupled $\text{Co}_2\text{FeAl}/(\text{Ga},\text{Mn})\text{As}$ heterostructure. When τ vanishes, the magnetization \mathbf{M} is away from its original equilibrium orientation and starts to precess around \mathbf{H}_{eff} , as depicted in Fig. 1(a). The ultrafast spin precession excitation is described by a modified Landau-Lifshitz-Gilbert (LLG) equation with the additional torque term [17]:

$$\frac{\partial \mathbf{M}}{\partial t} = -\gamma (\mathbf{M} \times \mathbf{H}_{\text{eff}}) + \alpha \mathbf{M} \times \frac{\partial \mathbf{M}}{\partial t} + \tau(t) \quad (1)$$

where γ is gyromagnetic ratio and α is the Gilbert damping constant.

Figure 1 (d) displays the TRMOKE result from the $\text{Co}_2\text{FeAl}/(\text{Ga},\text{Mn})\text{As}$ bilayer at 5 K with the pump pulse fluence $I_0 = 5 \mu\text{J}/\text{cm}^2$ and magnetic field $H = 227$ Oe. Here, four mutually competing dynamic magnetization processes are observed: (i) an initial ~ 20 picosecond demagnetization (-0.2 mdeg), (ii) followed by a distinct magnetization rise on a 100 ps time scale (0.2 mdeg), (iii) the magnetization starts precessing in a damped circling way as described by Eq. 1 and (iv) the demagnetization predominates again after the decaying of magnetization enhancement.

The fast Fourier transform (FFT) of the TRMOKE signal is shown in the inset of Fig. 1(d), indicating a precession frequency of around 11 GHz, which is similar to that observed from the single Co_2FeAl layer [25]. Besides, the uniform magnetization precession exists up to the room temperature where ferromagnetic or-

der is absent in the (Ga,Mn)As layer. Moreover, since (Ga,Mn)As has much smaller saturated magnetization and magnetic anisotropy, its magnetization precession frequency is much smaller than the observed precession frequency.[26, 27] Although the (Ga,Mn)As layer contributes to the overall MOKE signal of the bilayer, this contribution does not affect the amplitude of the oscillating component of the TRMOKE signal originating from magnetization precession in the Co_2FeAl layer (see Supplementary Note 6). Therefore, we ascribe the precession signals observed in the $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ bilayer to the uniform magnetization precession of Co_2FeAl , though the overall TRMOKE signal encompasses the contribution of both layers.

Figure 1(e) shows TRMOKE results of Co_2FeAl thin film directly grown on GaAs (001) substrate (see Methods), which are remarkably different from those of $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ bilayer. First, very little picosecond demagnetization and no magnetization rise on a 100-ps time scale are observed. Second, almost no coherent spin precession signal can be observed with the same low excitation fluence ($I_0 = 5 \mu\text{J}/\text{cm}^2$) as the measurement on $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ bilayer, and small oscillations are noticeable only at higher pump energy density, $I = 15I_0$. Compared with the reference sample $\text{Co}_2\text{FeAl}/\text{GaAs}$, it is pronounced that the excitation efficiency is improved by 30-40 times in the $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ bilayer. In order to elucidate the enhanced optical excitation mechanism, fluence-, field- and temperature-dependent TRMOKE measurements are carried out.

Pump-fluence-, field-, and temperature-dependent TRMOKE studies

Figure 2(a) and 2(b) present TRMOKE results from $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ bilayer as a function of pump-pulse fluence with $H = 227 \text{ Oe}$ applied along the hard axis [1-10]. The precession amplitude A increases with increasing pump-pulse fluence and tends to saturate at higher pump fluences, due to thermal effect with high laser power. Figure 2(c) and 2(d) display the extracted values of precession frequency f and amplitude A , respectively, as a function of H applied along the intermediate axis [100] and hard axis [1-10].

The frequency f is well fitted with Eq. 1 (red and blue curve) to derive the magnetic anisotropies and the exchange-coupling energy J_{ex} (see Supplementary Note 2). At $T = 7 \text{ K}$, The magnitude of $J_{\text{ex}} = 326,056 \text{ erg}/\text{cm}^3$ is comparable to the cubic anisotropy, $K_1 = 290,000 \text{ erg}/\text{cm}^3$, indicating strong ferromagnetic exchange coupling in the $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ bilayer. The exchange-coupling term J_{ex} increases moderately from 300 K to around 50 K, and then increases significantly afterwards (see Supplementary Note 4), which suggests a strong

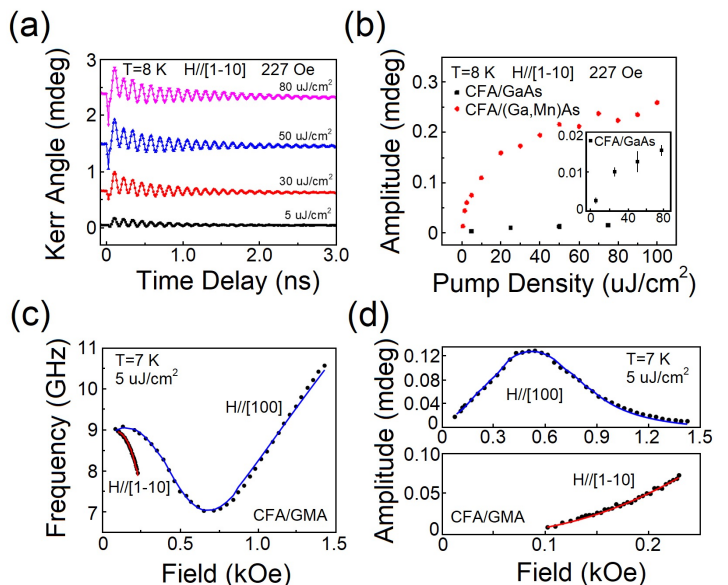


FIG. 2. Fluence and field dependent TRMOKE studies. (a) TRMOKE results from $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ bilayer at 8 K with \mathbf{H} applied along hard axis [1-10] for different pump-energy densities. (b) Precession amplitude as a function of pump-energy density for $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ (red dots) and $\text{Co}_2\text{FeAl}/\text{GaAs}$ (blue dots), respectively. The inset shows close-up of precession amplitude in single Co_2FeAl film. (c) Precession frequency as a function of applied field along intermediate axis [100] and hard axis [1-10]. The black dots show the experimental result. The blue and red curves are fits of LLG equation (Supplementary). (d) Precession amplitude as a function of the applied magnetic field for [100] (top) and [1-10] direction (bottom), respectively. The black points show the experimental result. The blue and red lines represent fits (Supplementary).

exchange-coupling between Co_2FeAl and (Ga,Mn)As.

The simulation of A versus H (red and blue curve), where A is assumed to be proportional to the deviation of equilibrium magnetization $\Delta\varphi$, also agrees well with the experimental data (black dots). At all temperatures, only by considering the enhancement of exchange coupling energies can the experimental data of A versus H satisfy the theoretical model (see Supplementary Note 5). This evinces that such strong excitations of magnetization precession originate from the photo-enhancement of interfacial exchange coupling, where the enhancement ratio, i.e., $\Delta J_{\text{ex}}/J_{\text{ex}}$, is around 20% at $T = 7 \text{ K}$, 10% at $T = 50 \text{ K}$ and 5% at $T = 300 \text{ K}$.

Figure 3 shows the temperature dependence of the magnetization precession in $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ bilayer with H applied along the hard axis [1-10]. The TRMOKE results at $T = 5 \text{ K}$ and 25 K clearly exhibit the photo-induced transient enhancement of magnetization precession amplitude, while at $T = 80 \text{ K}$, 170 K and 260 K the transient deviation of magnetization is almost absent (Fig. 3(a)). Figure 3(b) shows the temperature

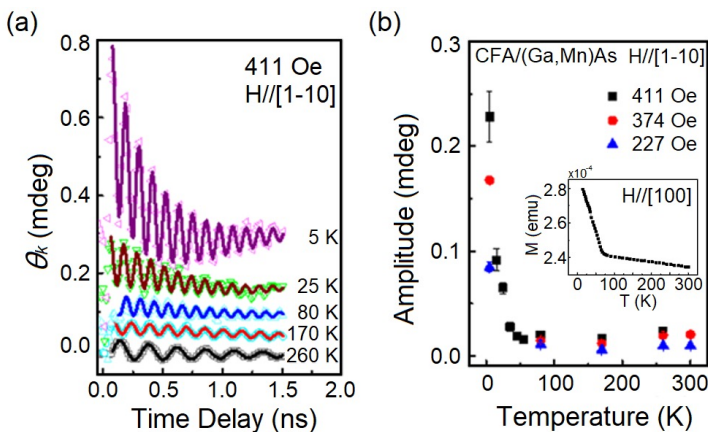


FIG. 3. Temperature dependent TRMOKE studies. (a) TRMOKE data from $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ bilayer at different temperatures: 5 K, 25 K, 80 K, 170 K and 260 K. (b) Precession amplitude as a function of temperature at different applied fields: 227 Oe (blue triangles), 374 Oe (red circles) and 411 Oe (black squares). Inset: temperature dependence of static magnetization in $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ bilayer.

dependence of the precession amplitude A for three applied fields: 227 Oe, 374 Oe and 411 Oe. It is prominent that: (i) when the temperature T is below the Curie temperature of $(\text{Ga,Mn})\text{As}$ $T_c = 50$ K, the precession amplitude A rapidly decreases with increasing temperature; and (ii) when T is above T_c , A almost remains constant up to room temperature with a small magnitude. In addition, at $T = 5$ K, A strongly decreases with decreasing the external field (411 Oe to 227 Oe), while such a reduction is much smaller when $T > 50$ K. On the other hand, the precession amplitude of the reference sample $\text{Co}_2\text{FeAl}/\text{GaAs}$ remains unchanged for $T = 5$ K – 300 K, and is 3 – 4 times smaller than that $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ even when $T \geq 50$ K. Therefore, these facts suggest that the proximity effect in $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ plays an essential role in the excitation of magnetization precession that is due to the optical modulation of the interfacial exchange coupling.

DISCUSSION

Three aspects are carefully considered to elucidate the pronounced magnetization precession excitation mechanism. First, a comparison among magnetization precessions of $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ and $\text{Co}_2\text{FeAl}/\text{GaAs}$ heterostructures indicates a photo-induced modulation on the interfacial exchange coupling between the Co_2FeAl and $(\text{Ga,Mn})\text{As}$ layer. If such a modulation is a reduction, we should expect precession amplitudes increase dramatically with temperature increasing near and above 50 K. Because the interfacial exchange coupling will be modulated more significantly at higher temperatures con-

sidering it should have a similar trend as frequency (see Supplementary Note 3). However, the temperature dependency of precession amplitude is inconsistent with our observations under such circumstances. Second, the precession amplitudes A versus applied fields H at all temperatures satisfy our theoretical model only when increments are included in interfacial exchange coupling energies J_{ex} , rather than magnetic anisotropies or saturation magnetizations. Third, the pump fluence of $5 \mu\text{J}/\text{cm}^2$ is too small to induce heat on the lattice (see Supplementary Note 7), making it impossible to modulate the magnetic anisotropies of Co_2FeAl with thermal effect. Last, since the temperature dependence of the precession amplitude A [Fig. 3(b)] follows the same trend with the increase of magnetization, one may think that the photo-enhanced ferromagnetism in the $(\text{Ga,Mn})\text{As}$ layer could correlate with the high-efficient excitation of coherent spin precession. However, such a correlation should be insignificant as the photo-enhanced magnetization of $(\text{Ga,Mn})\text{As}$ is less than 0.2% with a similar pump fluence and temperature.[28] Therefore, we attribute the optical excitation mechanism of the observed magnetization precession in the $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ heterostructure to a photo-enhanced interfacial exchange interaction. The mechanism is discussed concretely in the following.

A Schottky-barrier space charge layer forms at the heterojunction and the valence band of $(\text{Ga,Mn})\text{As}$ is near the Fermi level due to its p-type semiconductor nature, as depicted in Fig. 4(b). Under the low-fluence, near-infrared pump-light excitation, a fast demagnetization process occurs in the $(\text{Ga,Mn})\text{As}$ layer during $\Delta t < 20$ ps due to the rapid spin-flip scattering of the optically generated hot hole carriers with the localized Mn moments, which corresponds to the initial dip in Fig. 1(d). At extended time delays ($20 \text{ ps} < \Delta t < 100 \text{ ps}$), the hole-mediated ferromagnetic ordering enhances as the optically generated, thermalized holes populate the spin-split bands of the $(\text{Ga,Mn})\text{As}$ layer. More pronouncedly, the photoexcited excess electrons, as shown in Fig. 4b, transfer to the interfacial Co_2FeAl layer and fill the majority-spin bands, enhancing the magnetization of Co_2FeAl layer at the interface. This results in both a spin current and a charge current that transfers spin angular momentum into the Co_2FeAl layer, modulating the FM order of Co_2FeAl at the interface and thus enhancing the interfacial exchange coupling. On the other hand, the spin injection to the Co_2FeAl layer from the $(\text{Ga,Mn})\text{As}$ layer may also produce a spin torque on the Co_2FeAl magnetization due to different spin-polarization of the two FM layers. The change of the effective field direction in the Co_2FeAl layer gives rise to a transient torque on its magnetization and therefore prominently increases the amplitude of the photo-excited FM spin precession.

At larger time delays, the magnetization enhancement decays as the excess spin-up electrons in the Co_2FeAl layer recombines with the spin-polarized holes

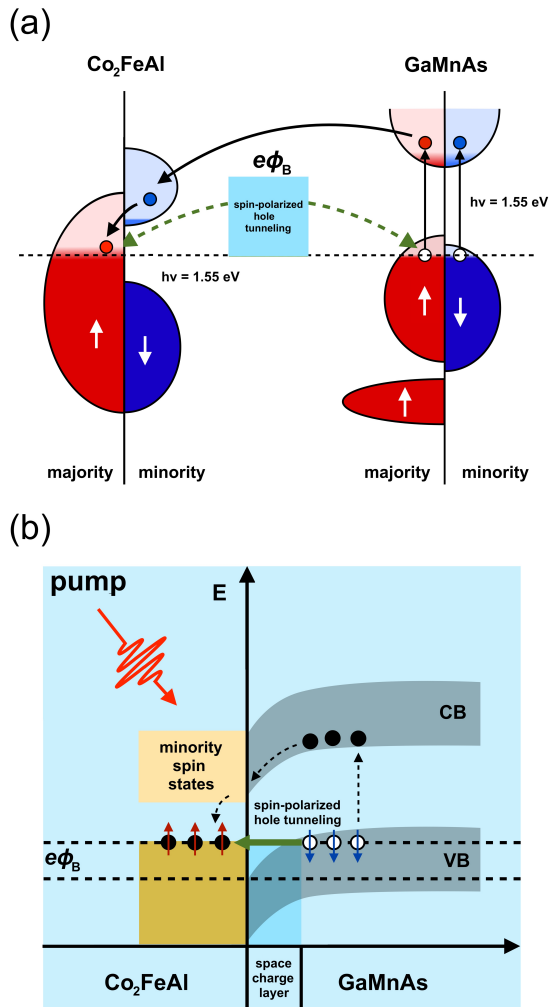


FIG. 4. Schematic of the modulation of interfacial exchange coupling via charge transfer to the majority spin states. Transfer and recombination process of photoexcited carriers in the $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ heterostructure in (a) the density of state and energy diagram and (b) the corresponding band lineup in real space along the normal to the surface z . Red and blue solid circles in (a) corresponds to the majority- and minority-spin electrons, respectively. White and black solid circles in (b) denotes the holes and electrons, respectively.

in the $(\text{Ga,Mn})\text{As}$ through spin-polarized hole tunneling through the Schottky spacer, and the demagnetization in the $(\text{Ga,Mn})\text{As}$ layers predominates in the TRMOKE signal as the corresponding recovery process can be as long as 5 ns due to laser-induced heat effect on lattice. [29]

Lastly, although the ferromagnetic ordering in the $(\text{Ga,Mn})\text{As}$ layer is almost broken when $T > 50$ K, the coherent spin precession can still be excited in the Co_2FeAl layer with amplitude being 3 – 4 times larger than that of $\text{Co}_2\text{FeAl}/\text{GaAs}$. This consolidates our conclusion that the main contribution to the salient FM precession in Co_2FeAl is the modulation of J_{ex} by a photo-excited spin

current at the interface rather than the magnetization in the $(\text{Ga,Mn})\text{As}$ layer. It is noted that the magnetization precession amplitude A exhibits very little variation and remains considerable value with temperatures up to 300 K (Fig. 3(b)). Therefore, the spin polarization of the photo-generated holes should correspond to the FM order of $(\text{Ga,Mn})\text{As}$ at the interface, which exchange-couple with the Co_2FeAl layer via the magnetic proximity effect. In fact, Nie and coworkers have shown that even above the Curie temperature of $(\text{Ga,Mn})\text{As}$, the Mn spins in a 2.11-nm thick interfacial layer remain spin polarized up to 300 K [24].

CONCLUSION

In summary, the efficiency of coherent spin precession excitation by laser pulses is significantly improved in the $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ bilayer, where a large interfacial exchange-coupling establishes. The low-fluence, near-infrared pump-light excitation generates carriers in the $(\text{Ga,Mn})\text{As}$ layer, resulting in a charge/spin current to the Co_2FeAl majority spin states, alternating the FM order of Co_2FeAl and thus dynamically enhancing the exchange coupling at the interface. The photo-excited coherent spin precession lives up to room temperature, with the amplitude dropping significantly around the Curie temperature of $(\text{Ga,Mn})\text{As}$, indicating that the proximity effect plays an essential role in the optical excitation mechanism of coherent spin precession. Our results highlight the importance of considering the range of interfacial exchange interactions in ferromagnetic heterostructures and promote the development of low-energy consumption magnetic device concepts for fast spin manipulation.

METHODS

Sample fabrication. $\text{Co}_2\text{FeAl}/(\text{Ga,Mn})\text{As}$ bilayers are grown on GaAs (001) substrates by molecular-beam epitaxy (MBE) [24]. The thickness of Co_2FeAl and $\text{Ga}_{1-x}\text{Mn}_x\text{As}$ ($x = 0.07$) layers are 10 nm and 150 nm, respectively. The bilayers are capped with 2-nm thick Al layer to avoid oxidation. For the reference, a single 10-nm thick Co_2FeAl layer is grown on GaAs (001) substrate by MBE. Reflection high-energy electron diffraction (RHEED) patterns, high-resolution double-crystal x-ray diffraction (DCXRD) measurements, and high-resolution cross-sectional transmission electron microscopy (HRTEM) reveal high-quality, single-crystalline, epitaxial growth of the Co_2FeAl and $(\text{Ga,Mn})\text{As}$ films [24].

Magnetic characterization. Magnetic measurements are conducted from 300 to 5 K in a magnetic field of 1 T using a SQUID magnetometer [24]. The

magnetic coupling at the interface between Co₂FeAl and (Ga,Mn)As layers is probed with element-resolved XMCD measurements [24]. Ab-initio density functional calculations are performed to support the experimental results [24].

MOKE experiments. The ferromagnetic magnetization of the exchange-coupled Co₂FeAl/(Ga,Mn)As bilayer is measured using the longitudinal MOKE setup. The sample is illuminated with p-polarized light and the reflected s-polarized light is detected with a photodiode. The magnetic field is applied along the in-plane [110] or [-110] crystallographic directions. The measurements are conducted from 5 K to above room temperature.

TRMOKE experiments. For the pump-probe TRMOKE measurements, a Ti:sapphire oscillator laser system is employed, which produces 150-fs pulses at 800-nm wavelength with a repetition rate of 80 MHz. The probe fluence is fixed at $\sim 0.5 \mu\text{J}/\text{cm}^2$ and the pump fluence varies from 0.5 - 100 $\mu\text{J}/\text{cm}^2$. The probe pulses ($\lambda = 800 \text{ nm}$) utilize the balanced detection technique with a half-wave plate and Wollaston prism to investigate the transient magnetic state change along longitudinal and polar directions. The measurements are conducted from 5 K to above room temperature.

Data analysis and simulations. The Origin 8.5 software is employed to fit the raw TRMOKE data utilizing the build-in non-linear-fit function. The software provides the uncertainties of precession amplitude A and precession frequency f from least-square fitting. The Matlab software is utilized to fit the change of f and A as functions of H with least-square methods (see Supplementary). The error-propagation method is used to estimate the uncertainties of interfacial exchange-coupling strength and magnetic anisotropy fields.

DATA AVAILABILITY

The data that support the findings of this study are available from the corresponding author upon reasonable request.

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AUTHOR CONTRIBUTIONS

X. L., P. L., H. C. Y., J. H. Z., H. B. Z., and G. L. designed and analyzed the experiments. H. L. W., S. H. N., J. Y. S., and X. Z. Y. prepared the samples and carried out characterizations using MOKE, RHEED, and SQUID measurements. H. C. Y., J. Y. S., X. L., P. L., and F. J. performed the TRMOKE experiments. X. L., P. L., H. C. Y. and J. Y. S. conducted the data analysis and simulations. All authors discussed the results. X. L., P. L., J. H. Z., H. B. Z., and G. L. wrote the manuscript with contributions from all authors.

COMPETING INTERESTS

The authors declare no competing financial interests.

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